

# SD1014, SZESD1014

## ESD Protection Diode Array

### Low Capacitance ESD Protection Diode for High Speed Data Line

The ESD1014 surge protection is designed to protect high speed data lines from ESD, EFT, and lightning.

#### Features

- Low Capacitance (6 pF Maximum Between I/O Lines and GND)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body model and Class C (Exceeding 400 V) per Machine Model
- Protection for the Following IEC Standards:  
IEC 61000-4-2 (ESD) Level 4 – 30 kV (Contact)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb-Free Device

#### Typical Applications

- High Speed Communication Line Protection
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays
- T1/E1 and T3/E3
- 10/100/1000 Ethernet Protection
- Gigabit Ethernet Protection

#### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Power Dissipation	$P_{pk}$	450	W
Maximum Peak Pulse Current 8 x 20 $\mu\text{s}$ @ $T_A = 25^\circ\text{C}$	$I_{pp}$	30	A
Operating Junction Temperature Range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Lead Solder Temperature – Maximum (10 Seconds)	$T_L$	260	$^\circ\text{C}$
Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Contact (ESD)	ESD	16000 400 30000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

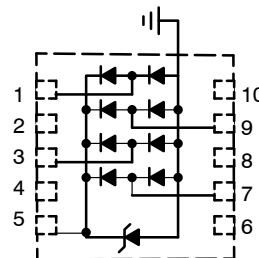


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## LOW CAPACITANCE DIODE SURGE PROTECTION ARRAY

### PIN CONFIGURATION AND SCHEMATIC



UDFN10  
CASE 517AN

### MARKING DIAGRAM



- 1014 = Specific Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package

### ORDERING INFORMATION

Device	Package	Shipping†
ESD1014MUTAG	UDFN10 (Pb-Free)	3000 / Tape & Reel
SZESD1014MUTAG	UDFN10 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	$V_{RWM}$	(Note 1)			3.3	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{ mA}$ , (Note 2)	5.0	5.3		V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3\text{ V}$			5.0	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{ A}$ , pin 5 to GND			6.2	V
Clamping Voltage	$V_C$	$I_{PP} = 1\text{ A}$			7.5	V
Clamping Voltage	$V_C$	$I_{PP} = 10\text{ A}$			9.0	V
Clamping Voltage	$V_C$	$I_{PP} = 25\text{ A}$			11	V
Maximum Peak Pulse Current	$I_{PP}$	$8 \times 20\ \mu\text{s}$ Waveform			30	A
Junction Capacitance	$C_J$	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ between I/O Pins and GND		3.8	5.0	pF
Junction Capacitance	$C_J$	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ between I/O Pins		1.5	3.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Surge protection devices are normally selected according to the working peak reverse voltage ( $V_{RWM}$ ), which should be equal or greater than the DC or continuous peak operating voltage level.
- $V_{BR}$  is measured at pulse test current  $I_T$ .

## TYPICAL PERFORMANCE CURVES

( $T_J = 25^\circ\text{C}$  unless otherwise noted)

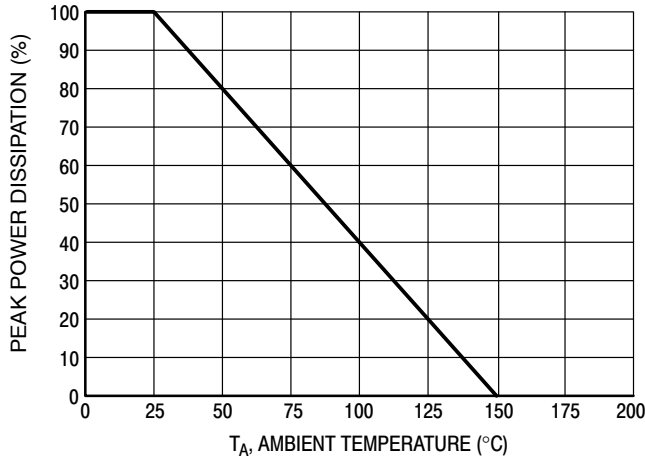


Figure 1. Pulse Derating Curve

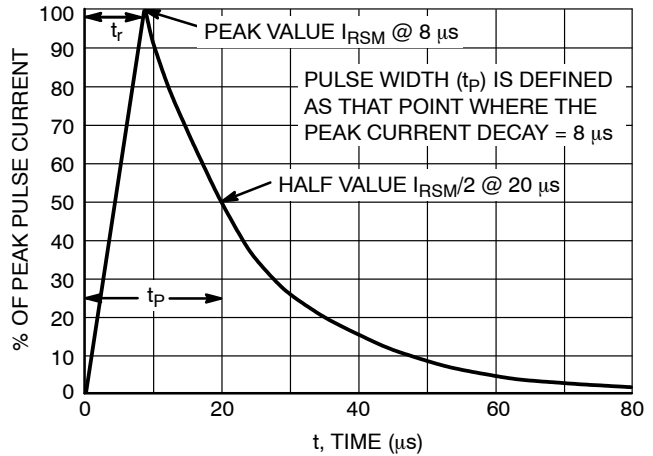
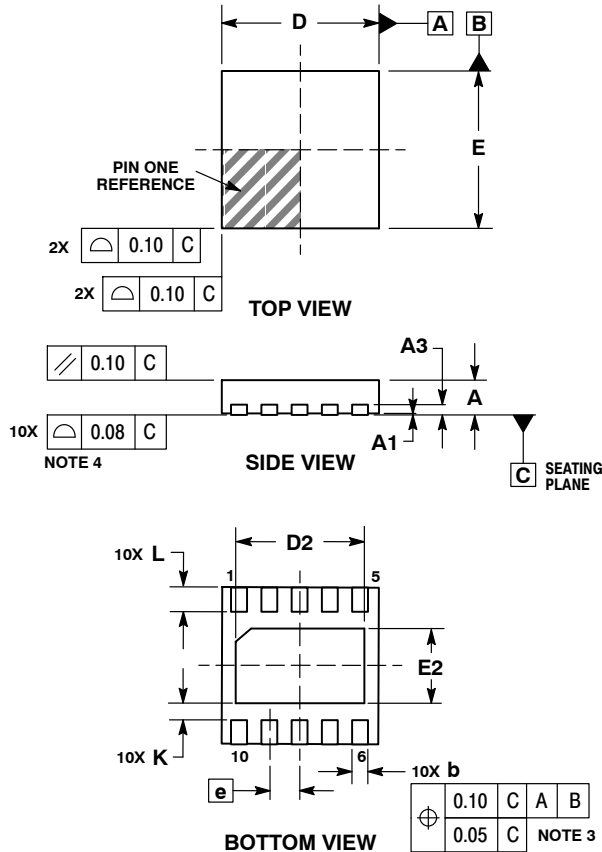


Figure 2.  $8 \times 20\ \mu\text{s}$  Pulse Waveform

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## PACKAGE DIMENSIONS

UDFN10 2.6x2.6, 0.5P  
CASE 517AN  
ISSUE B

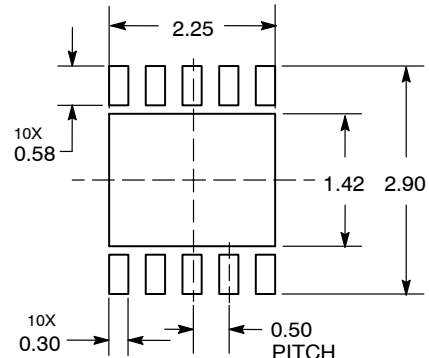


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.20	0.30
D	2.60 BSC	
D2	2.00	2.25
E	2.60 BSC	
E2	1.11	1.36
e	0.50 BSC	
K	0.20	---
L	0.30	0.40

### SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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